N-Channel 30-V (D-S) 175°C MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A)[a]
30	0.0043 @ V_{GS} = 10 V	33
	0.0065 @ V_{GS} = 4.5 V	27

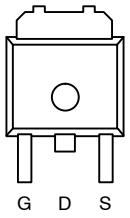
FEATURES

- TrenchFET® Power MOSFET
- 175°C Junction Temperature
- Optimized for Low-Side Synchronous Rectifier Operation
- 100% R_g Tested

APPLICATIONS

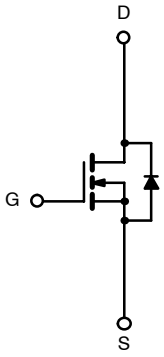
- DC/DC Converters
- Synchronous Rectifiers

TO-252



Top View

Drain Connected to Tab



N-Channel MOSFET

Ordering Information: SUD70N03-04P

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C UNLESS OTHERWISE NOTED)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	±20	
Continuous Drain Current[a]	T_A = 25°C	I_D	33	A
	T_C = 25°C		70[b]	
Pulsed Drain Current		I_{DM}	100	
Continuous Source Current (Diode Conduction)[a]		I_S	8.3[a]	
Maximum Power Dissipation	T_C = 25°C	P_D	88	W
	T_A = 25°C		8.3[a]	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	–55 to 175	°C

THERMAL RESISTANCE RATINGS

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient[a]	t ≤ 10 sec	R_{thJA}	15	18	°C/W
	Steady State		40	50	
Maximum Junction-to-Case		R_{thJC}	1.2	1.5	

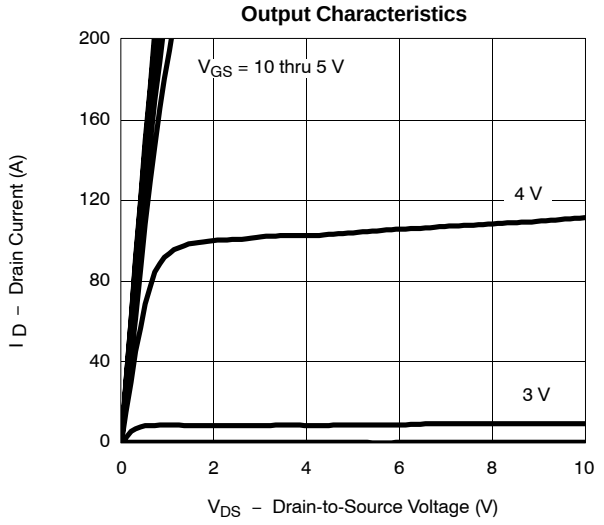
Notes
a. Surface Mounted on FR4 Board, t ≤ 10 sec.
b. Limited by package.

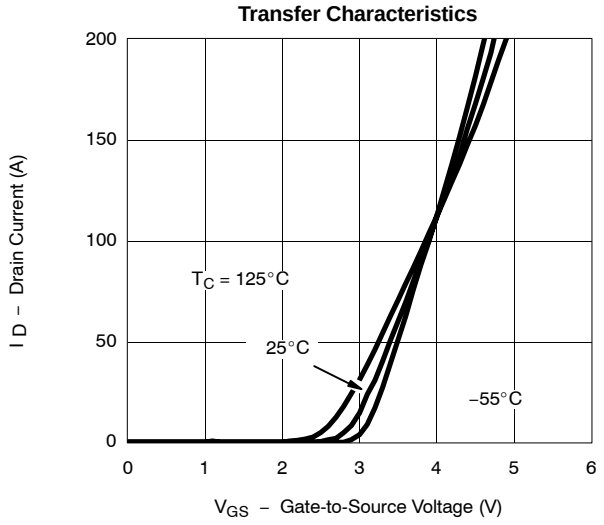
SPECIFICATIONS (T_J = 25°C UNLESS OTHERWISE NOTED)

Parameter	Symbol	Test Condition	Min	Typ[a]	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS} = 0 V, I_D = 250 μA	30			V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 μA	1.0		3.0	
Gate-Body Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ±20 V			±100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 30 V, V_{GS} = 0 V			1	μA
		V_{DS} = 30 V, V_{GS} = 0 V, T_J = 125°C			50	
On-State Drain Current[b]	$I_{D(on)}$	V_{DS} = 5 V, V_{GS} = 10 V	50			A
Drain-Source On-State Resistance[b]	$r_{DS(on)}$	V_{GS} = 10 V, I_D = 20 A		0.0035	0.0043	Ω
		V_{GS} = 10 V, I_D = 20 A, T_J = 125°C			0.007	
		V_{GS} = 4.5 V, I_D = 20 A		0.0051	0.0065	
Forward Transconductance[b]	g_{fs}	V_{DS} = 15 V, I_D = 20 A	20			S
Dynamic[a]						
Input Capacitance	C_{iss}	V_{GS} = 0 V, V_{DS} = 25 V, f = 1 MHz		5100		pF
Output Capacitance	C_{oss}			860		
Reverse Transfer Capacitance	C_{rss}			430		
Gate Resistance	R_g	f = 1 MHz	0.5	1.0	1.5	Ω
Total Gate Charge[c]	Q_g	V_{DS} = 15 V, V_{GS} = 10 V, I_D = 50 A		90	135	nC
Gate-Source Charge[c]	Q_{gs}			18		
Gate-Drain Charge[c]	Q_{gd}			16		
Turn-On Delay Time[c]	$t_{d(on)}$	V_{DD} = 15 V, R_L = 0.3 Ω I_D ≅ 50 A, V_{GEN} = 10 V, R_g = 2.5 Ω		12	20	ns
Rise Time[c]	t_r			12	20	
Turn-Off Delay Time[c]	$t_{d(off)}$			40	60	
Fall Time[c]	t_f			10	15	
Source-Drain Diode Ratings and Characteristic (T_C = 25°C)						
Pulsed Current	I_{SM}				100	A
Diode Forward Voltage[b]	V_{SD}	I_F = 100 A, V_{GS} = 0 V		1.2	1.5	V
Source-Drain Reverse Recovery Time	t_{rr}	I_F = 50 A, di/dt = 100 A/μs		40	80	ns

Notes
a. Guaranteed by design, not subject to production testing.
a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
a. Independent of operating temperature.

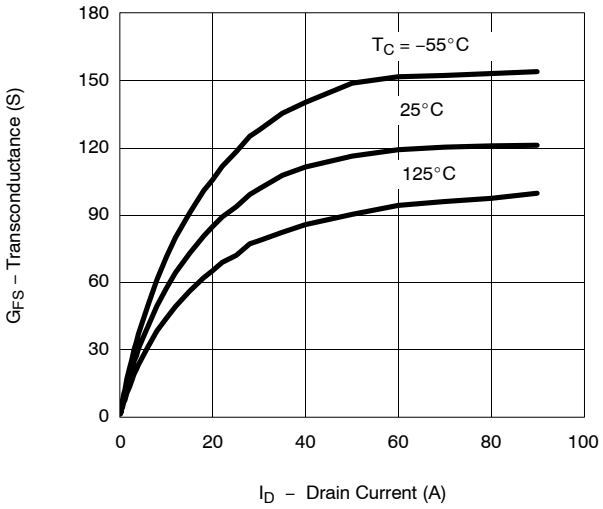
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



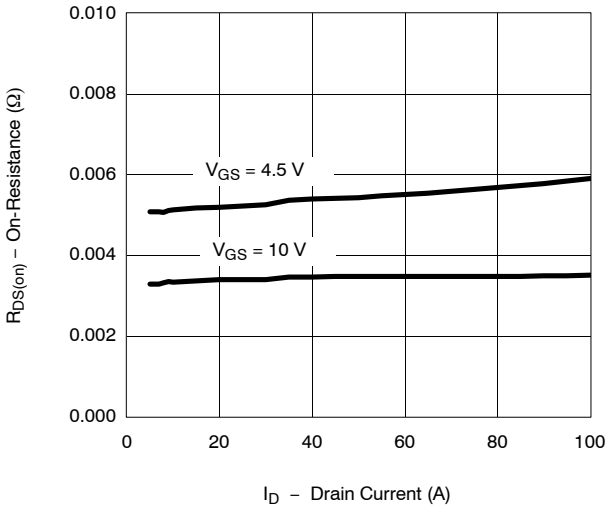


TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

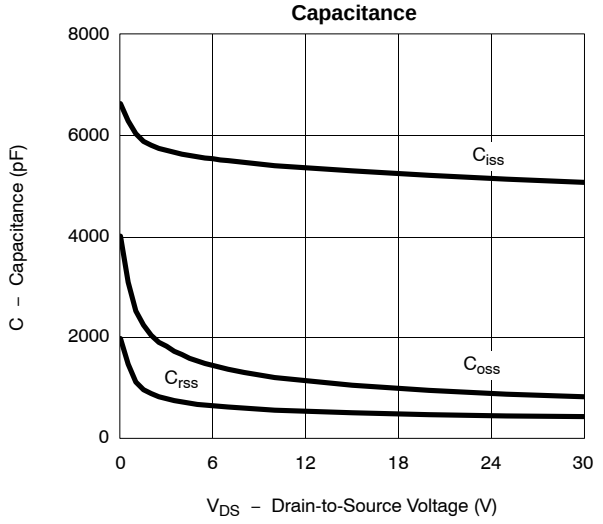
Transconductance



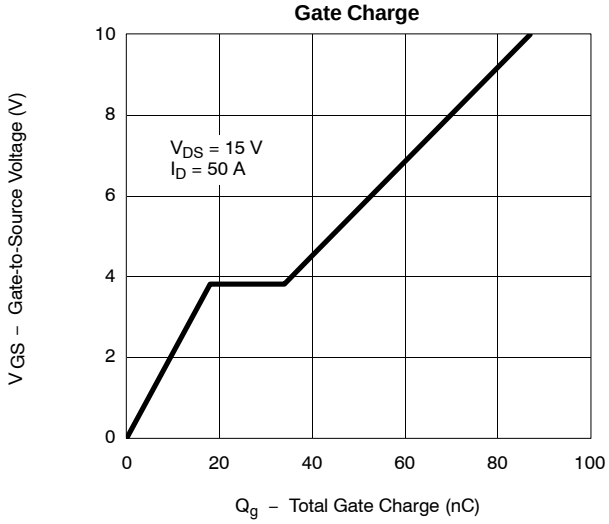
On-Resistance vs. Drain Current



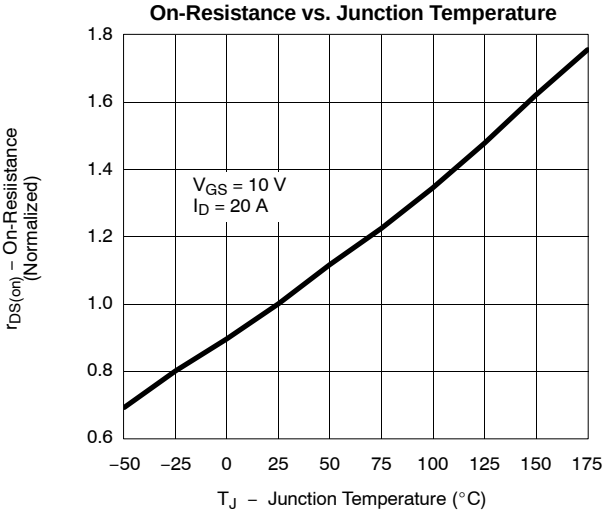
Capacitance



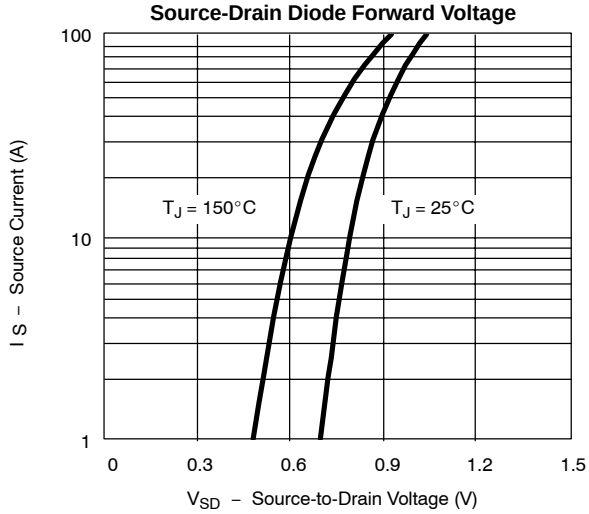
Gate Charge



On-Resistance vs. Junction Temperature

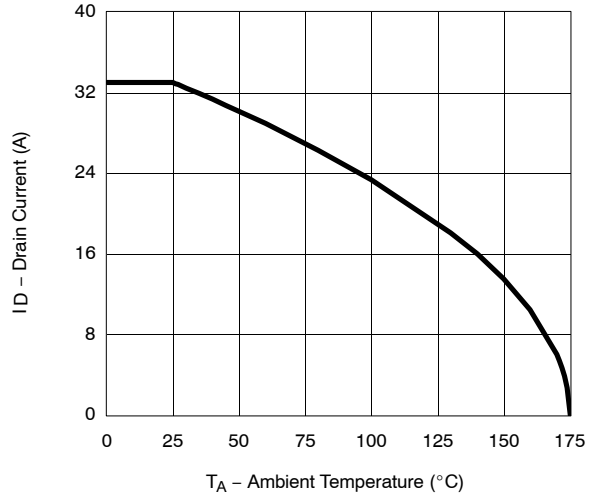


Source-Drain Diode Forward Voltage

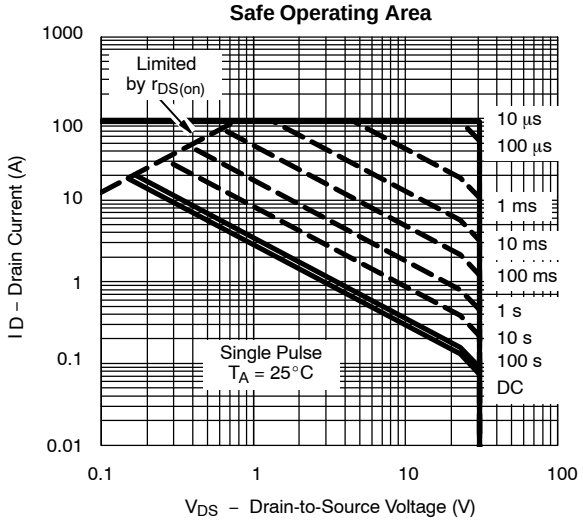


THERMAL RATINGS

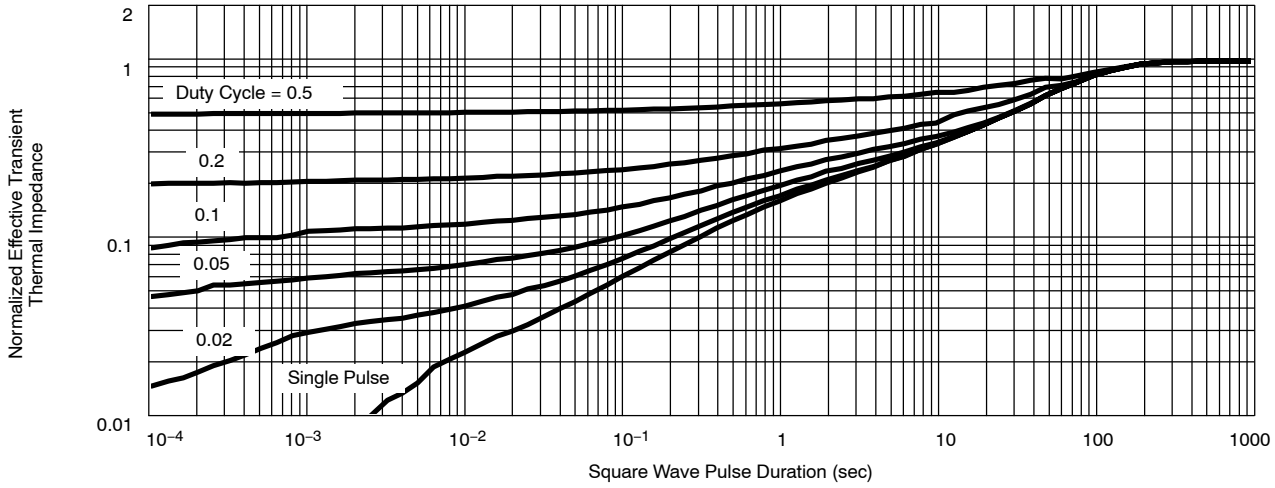
Maximum Avalanche and Drain Current vs. Ambient Temperature



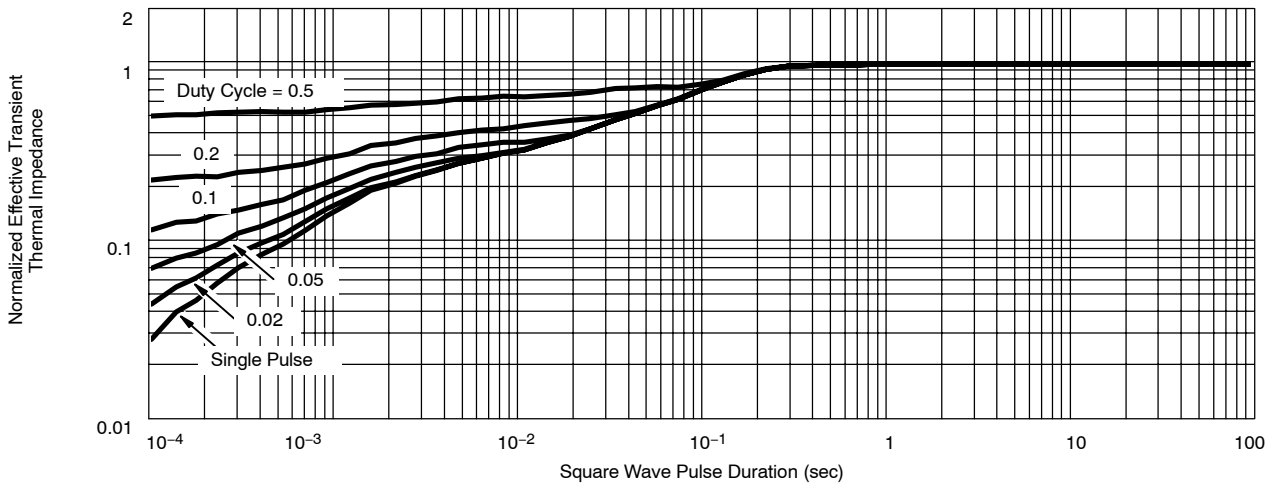
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case



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